NSN 5961-01-039-7389

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-039-7389 **Inclosure Material:** Metal **Overall Length:** Between 0.400 inches and 0.420 inches **Overall Height:** Between 0.115 inches and 0.128 inches **Overall Width:** Between 0.155 inches and 0.165 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 reverse voltage, peak **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 225.0 watts small-signal input power, common-collector pascal **Test Data Document:** 94990-48-+04261f drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: